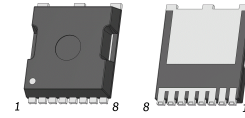


Silicon Carbide (SiC) JFET – EliteSiC, Power N-Channel, H-PDSO-F8, 750 V, 4.3 mohm

UJ4N075004L8S



H-PDSO-F8
CASE 740AA

Description

onsemi's UJ4N075004L8S is a 750 V, 4.3 mΩ high-performance Gen 4 normally-on SiC JFET transistor. This device exhibits ultra-low on resistance ($R_{DS(on)}$) in a compact H-PDSO-F8 package, making it an ideal fit to address the challenging thermal and space constraints of solid-state circuit breakers and relay applications. Additionally, the JFET is a robust device technology capable of the high-energy switching required in circuit protection applications.

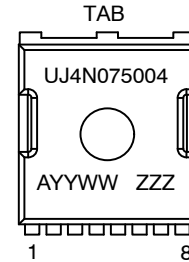
Features

- Single Digit On-Resistance in a H-PDSO-F8 SMDpackage
- Operating Temperature: 175 °C (Max)
- High Pulse Current Capability
- Excellent Device Robustness
- Silver-Sintered Die Attach for Excellent Thermal Resistance
- Short Circuit Rated
- This Device is Pb-Free, Halogen Free and is RoHS Compliant

Typical Applications

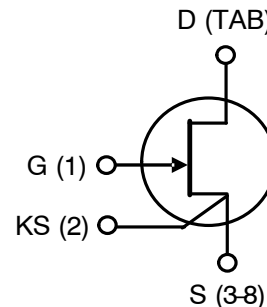
- Solid State / Semiconductor Circuit Breaker
- Solid State / Semiconductor Relay
- Battery Disconnects
- Surge Protection
- Inrush Current Control

MARKING DIAGRAM



UJ4N075004 = Specific Device Number
 A = Assembly Location
 YY = Year
 WW = Work Week
 ZZZ = Lot ID

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

UJ4N075004L8S

MAXIMUM RATINGS

Symbol	Parameter	Test Conditions	Value	Unit
V _{DS}	Drain-Source Voltage		750	V
V _{GS}	Gate-Source Voltage	DC	-30 to +3	V
		AC (Note 1)	-30 to +30	V
I _D	Continuous Drain Current (Note 2)	T _C < 145 °C	120	A
I _{DM}	Pulsed Drain Current (Note 3)	T _C = 25 °C	588	A
T _{SC}	Short Circuit Withstand Time	V _{DS} = 400 V, T _{J(START)} = 175 °C	5	μs
P _{tot}	Power Dissipation	T _C = 25 °C	1153	W
T _{J,max}	Maximum Junction Temperature		175	°C
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C
T _{solder}	Reflow Soldering Temperature	Reflow MSL 1	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- +30 V AC rating applies for turn-on pulses < 200 ns applied with external R_G > 1 Ω.
- Limited by Bondwires
- Pulse width t_p limited by T_{J,max}.

THERMAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
R _{θJC}	Thermal Resistance, Junction-to-Case		-	0.10	0.13	°C/W

ELECTRICAL CHARACTERISTICS (T_J = +25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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TYPICAL PERFORMANCE – STATIC

BV _{DS}	Drain-Source Breakdown Voltage	V _{GS} = -20 V, I _D = 2 mA	750	-	-	V
I _{DSS}	Total Drain Leakage Current	V _{DS} = 750 V, V _{GS} = -20 V, T _J = 25 °C	-	13	120	μA
		V _{DS} = 750 V, V _{GS} = -20 V, T _J = 175 °C	-	65	-	
I _{GSS}	Total Gate Leakage Current	V _{GS} = -20 V, T _J = 25 °C	-	0.1	100	μA
		V _{GS} = -20 V, T _J = 175 °C	-	0.3	-	μA
R _{DS(on)}	Drain-Source On-resistance	V _{GS} = 2 V, I _D = 80 A, T _J = 25 °C	-	4.3	-	mΩ
		V _{GS} = 0 V, I _D = 80 A, T _J = 25 °C	-	4.9	6.6	
		V _{GS} = 2 V, I _D = 80 A, T _J = 175 °C	-	9.9	-	
		V _{GS} = 0 V, I _D = 80 A, T _J = 175 °C	-	11.5	-	
V _{G(th)}	Gate Threshold Voltage	V _{DS} = 5 V, I _D = 180 mA	-8.3	-6.0	-3.7	V
R _G	Gate Resistance	f = 1 MHz, open drain	-	0.8	-	Ω

TYPICAL PERFORMANCE – DYNAMIC

C _{iss}	Input Capacitance	V _{DS} = 400 V, V _{GS} = -20 V, f = 100 kHz	-	3028	-	pF
C _{oss}	Output Capacitance		-	364	-	
C _{rss}	Reverse Transfer Capacitance		-	360	-	
C _{oss(er)}	Effective Output Capacitance, Energy Related	V _{DS} = 0 V to 400 V, V _{GS} = -20 V	-	448	-	pF
E _{oss}	C _{oss} Stored Energy	V _{DS} = 400 V, V _{GS} = -20 V	-	36	-	μJ
Q _G	Total Gate Charge	V _{DS} = 400 V, I _D = 80 A, V _{GS} = -18 V to 0 V	-	400	-	nC
Q _{GD}	Gate-Drain Charge		-	270	-	
Q _{GS}	Gate-Source Charge		-	60	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE DIAGRAMS

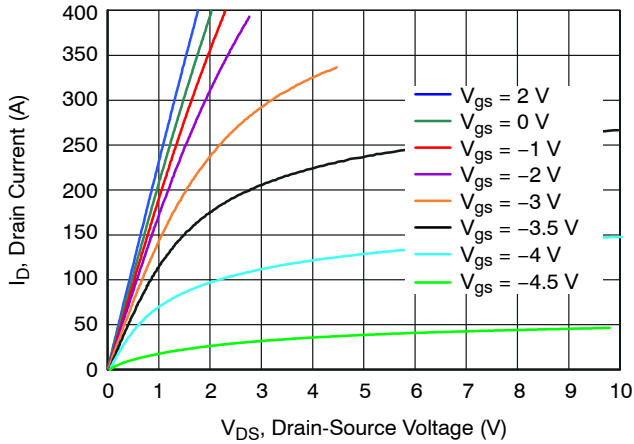


Figure 1. Typical Output Characteristics at $T_J = -55\text{ }^\circ\text{C}$, $t_p < 250\text{ }\mu\text{s}$

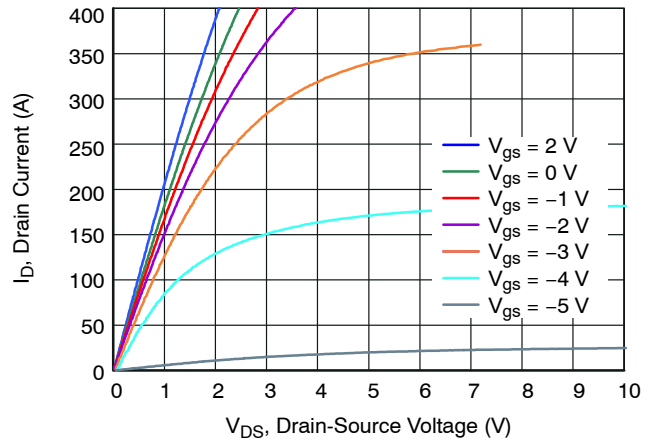


Figure 2. Typical Output Characteristics at $T_J = 25\text{ }^\circ\text{C}$, $t_p < 250\text{ }\mu\text{s}$

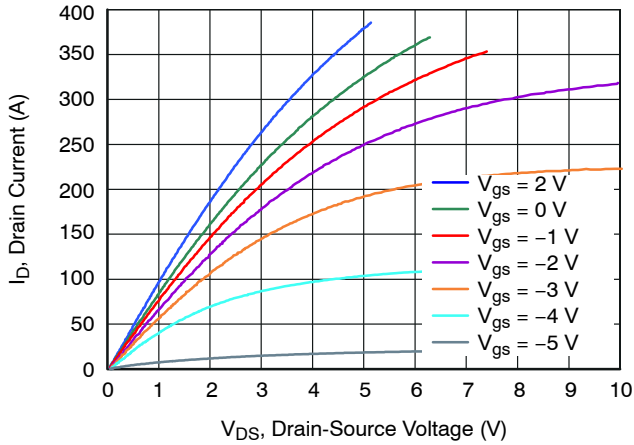


Figure 3. Typical Output Characteristics at $T_J = 175\text{ }^\circ\text{C}$, $t_p < 250\text{ }\mu\text{s}$

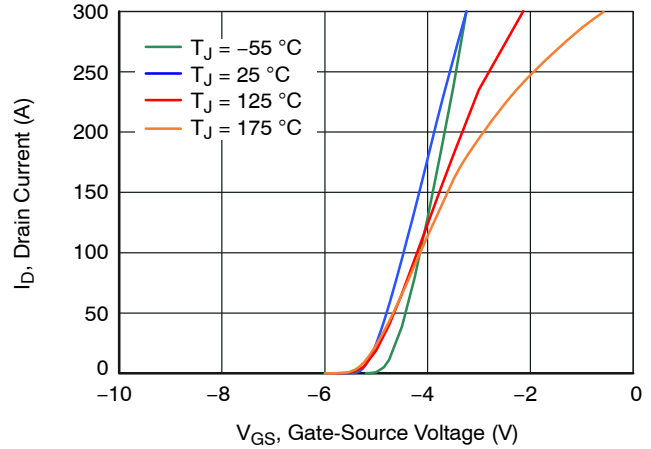


Figure 4. Typical Transfer Characteristics at $V_{DS} = 5\text{ V}$

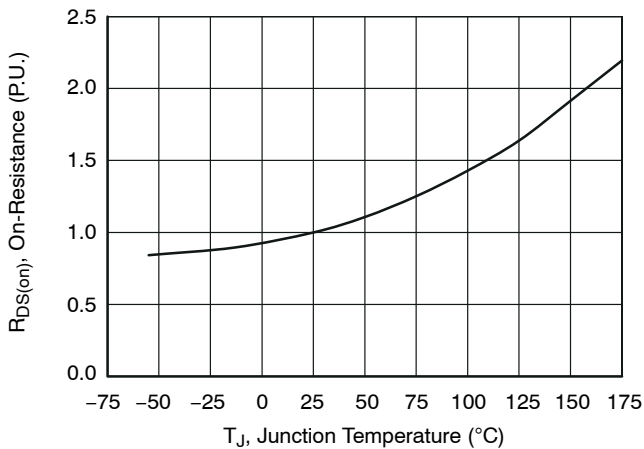


Figure 5. Normalized On-Resistance vs. Temperature at $V_{GS} = 0\text{ V}$ and $I_D = 80\text{ A}$

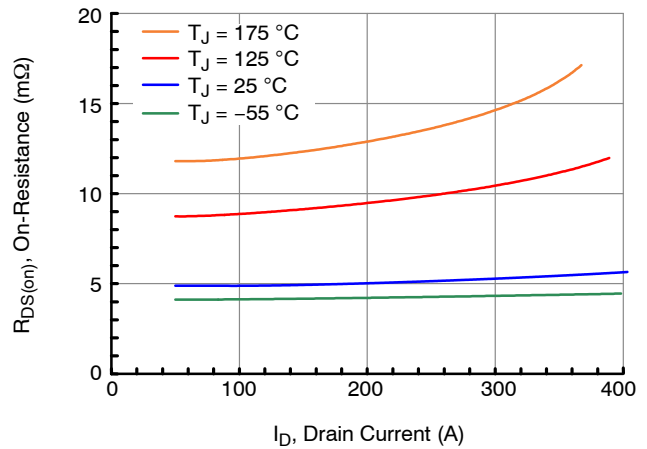


Figure 6. Typical Drain-Source On-Resistance $V_{GS} = 0\text{ V}$

TYPICAL PERFORMANCE DIAGRAMS (continued)

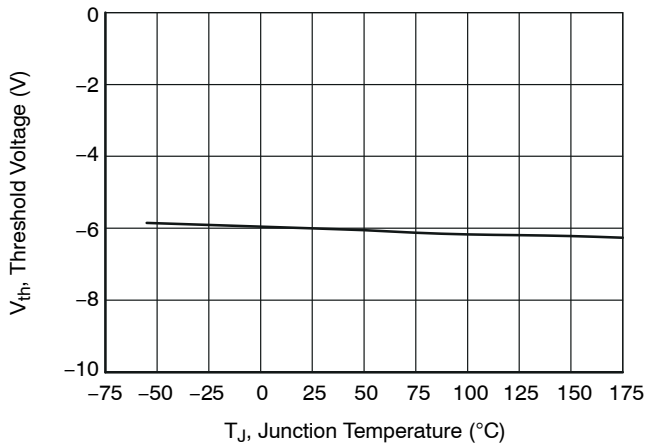


Figure 7. Threshold Voltage vs. Junction Temperature at $V_{DS} = 5\text{ V}$ and $I_D = 180\text{ mA}$

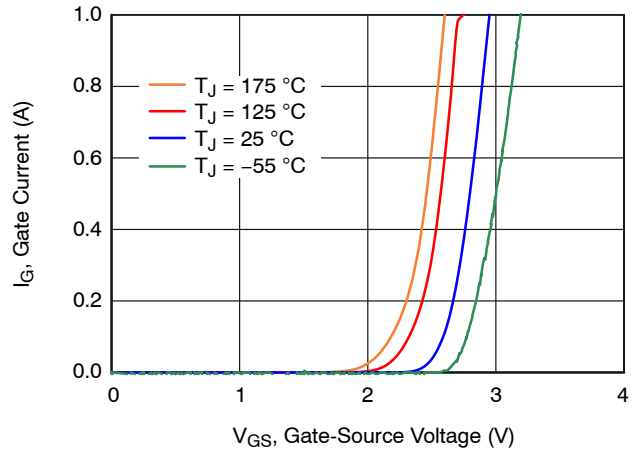


Figure 8. Typical Gate Forward Current at $V_{DS} = 0\text{ V}$

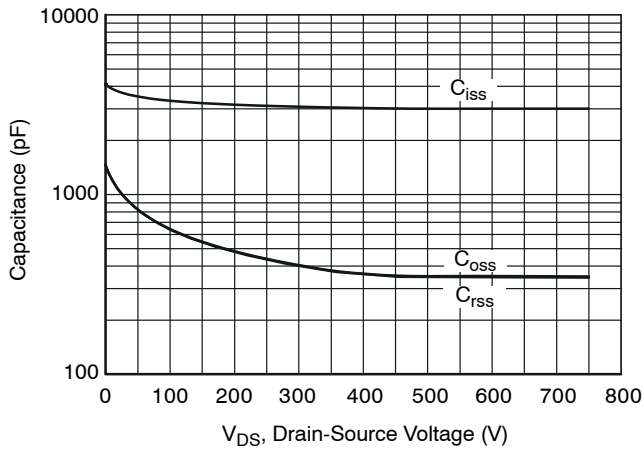


Figure 9. Typical Capacitances at $f = 100\text{ KHz}$ and $V_{GS} = -20\text{ V}$

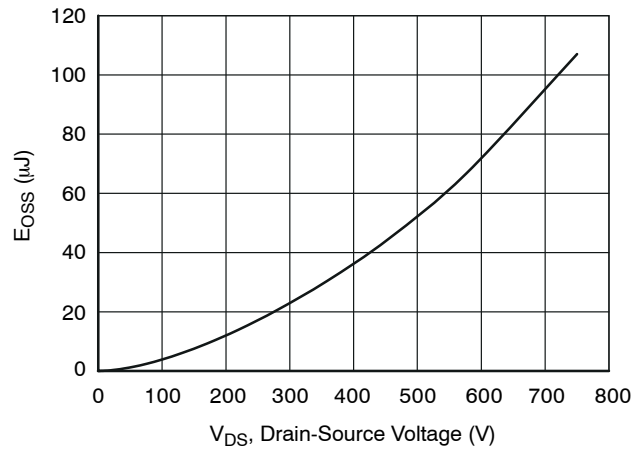


Figure 10. Typical Stored Energy in C_{OSS} at $V_{GS} = -20\text{ V}$

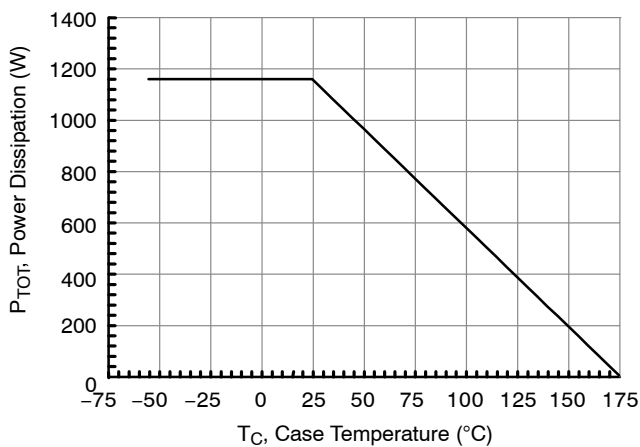


Figure 11. Total Power Dissipation

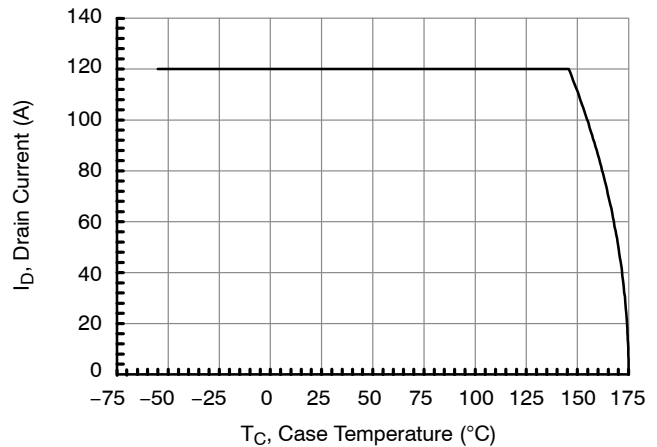


Figure 12. DC Drain Current Derating

TYPICAL PERFORMANCE DIAGRAMS (continued)

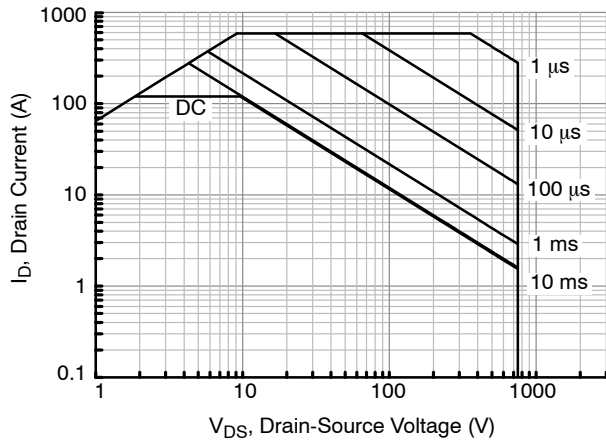


Figure 13. Safe Operation Area at $T_C = 25\text{ }^\circ\text{C}$, Parameter t_p

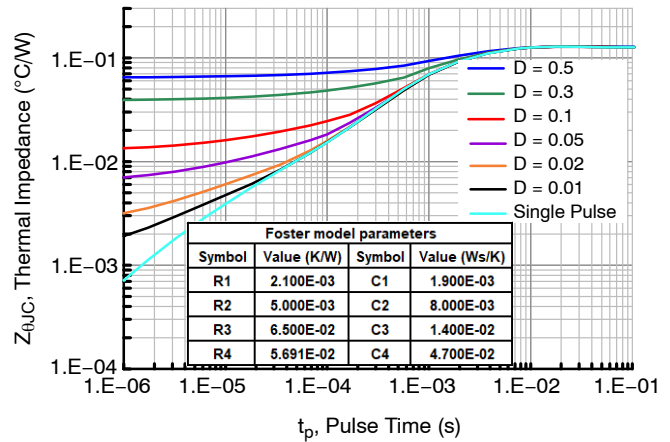


Figure 14. Maximum Transient Thermal Impedance

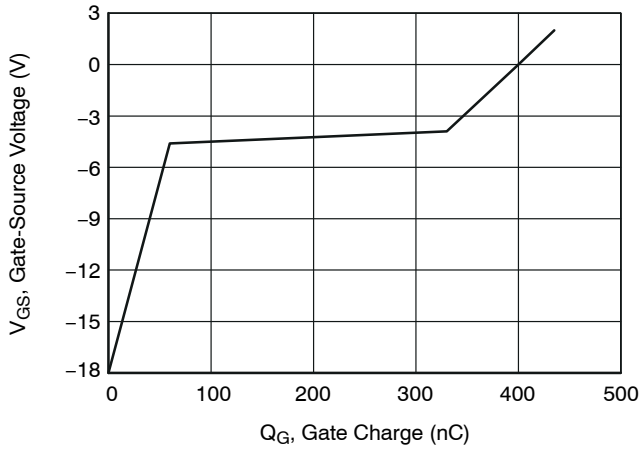


Figure 15. Typical Gate Charge at $V_{DS} = 400\text{ V}$ and $I_D = 80\text{ A}$

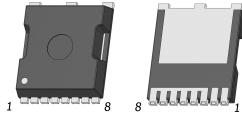
ORDERING INFORMATION

Part Number	Marking	Package	Shipping [†]
UJ4N075004L8S	UJ4N075004	H-PDSO-F8 (Pb-Free, Halogen Free)	2,000 / Tape and Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

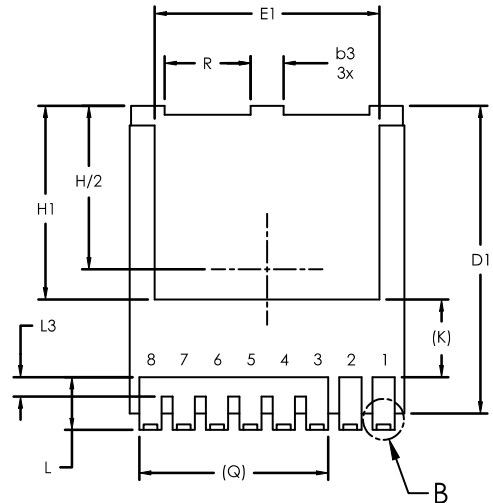
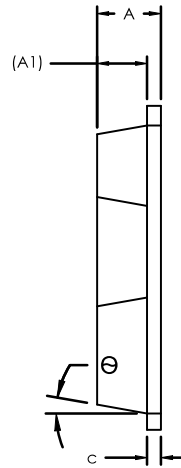
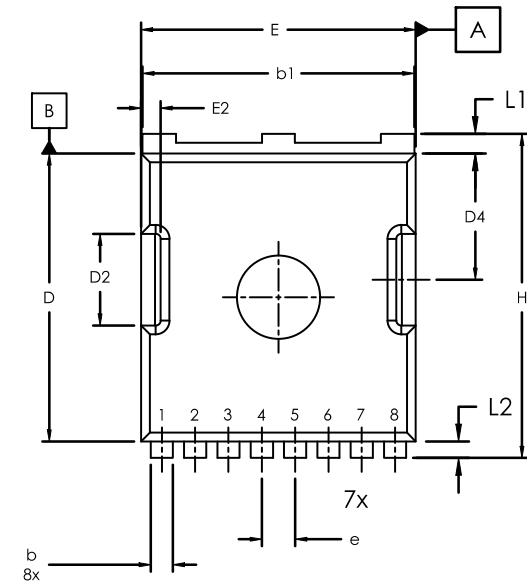
REVISION HISTORY

Revision	Description of Changes	Date
C	Acquired the original Qorvo JFET Division Data Sheet and updated the main document title to comply with onsemi standards for SiC products.	1/15/2025
2	Converted the Data Sheet to onsemi format.	5/7/2025

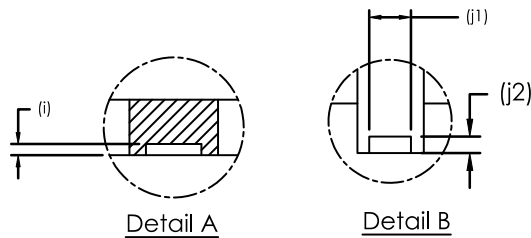
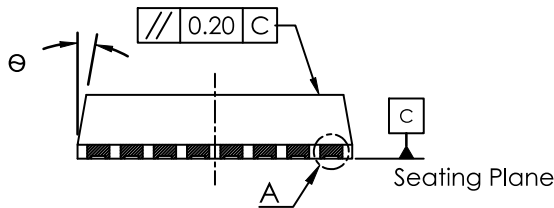


H-PDSO-F8 9.90x10.38x2.30, 1.20P
CASE 740AA
ISSUE B

DATE 24 JUN 2025



⊕	0.25(M)	C	A	B
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Note:

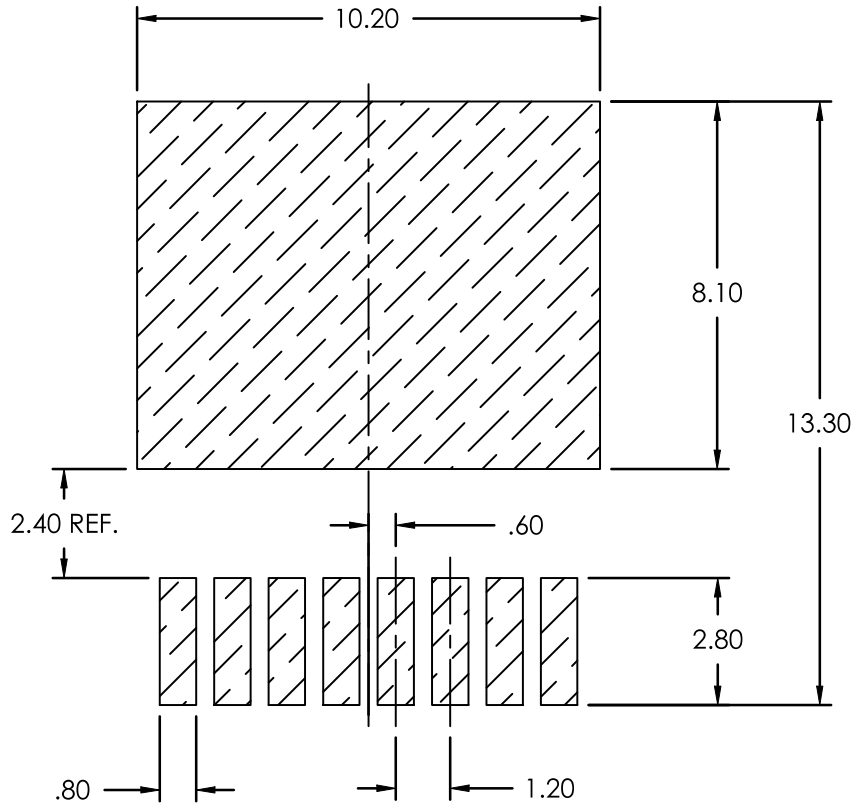
1. Dimensioning and tolerancing as per ASME Y14.5 - 2018
2. Controlling dimension : millimeters
3. Dimensions does not include Burrs and Mold Flashes

SYMBOL	Value		
	Min	Nom	Max
A	2.15	2.30	2.45
A1	1.80 REF		
b	0.65	0.80	0.90
b1	9.65	9.80	9.95
b3	1.10	1.20	1.30
c	0.40	0.50	0.60
D	10.18	10.38	10.58
D1	10.88	11.08	11.28
D2	3.15	3.30	3.45
D4	4.40	4.55	4.70
E	9.70	9.90	10.10
E1	7.95	8.10	8.25
E2	0.60	0.70	0.80
e	1.20 BSC		
H	11.48	11.68	11.88
H1	6.80	6.95	7.10
i	0.10 REF		
j1	0.46 REF		
j2	0.20 REF		
K	2.80 REF		
L	1.40	1.90	2.10
L1	0.50	0.70	0.90
L2	0.48	0.60	0.72
L3	0.30	0.70	0.80
Q	6.80 REF		
R	3.00	3.10	3.20
θ	10°		

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DESCRIPTION:	H-PDSO-F8 9.90x10.38x2.30, 1.20P	PAGE 1 OF 2

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